

**SCHOTTKY RECTIFIER**  
HIGH EFFICIENCY SERIES

**22GQ100**  
30 Amp, 100V

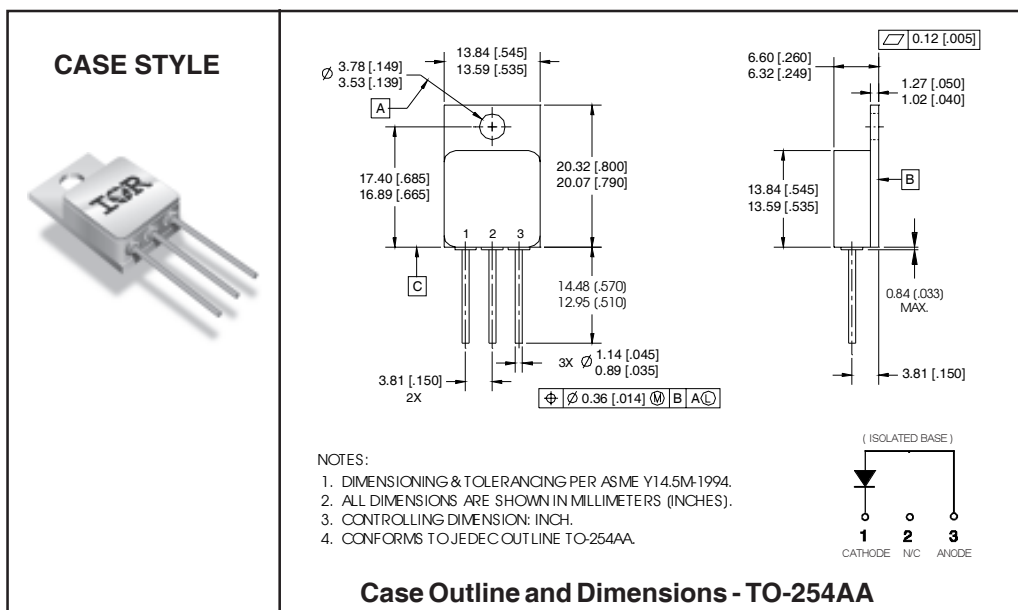
**Major Ratings and Characteristics**

Characteristics	Limits	Units
$I_{F(AV)}$ Rectangular Waveform	30	A
$V_{RRM}$	100	V
$I_{FSM}$ @ $t_p = 8.3ms$ half-sine	400	A
$V_F$ @ 20Apk, $T_J = 125^\circ C$	0.73	V
$T_J, T_{stg}$ Operating and storage	-55 to 150	$^\circ C$

**Description/Features**

The 22GQ100 Schottky rectifier has been expressly designed to meet the rigorous requirements of HiRel environments. It is packaged in the hermetic isolated TO-254AA package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source controlled drawings to TX, TXV and S levels.

- Hermetically Sealed
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long Term Reliability
- Electrically Isolated
- ESD Rating: Class 3A per MIL-STD-750, Method 1020



## 22GQ100

International  
**IOR** Rectifier

### Voltage Ratings

Parameters	22GQ100
$V_R$ Max. DC Reverse Voltage (V)	100
$V_{RWM}$ Max. Working Peak Reverse Voltage (V)	

### Absolute Maximum Ratings

Parameters	Limits	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current See Fig. 5	30	A	50% duty cycle @ $T_C = 113^\circ\text{C}$ , rectangular waveform
$I_{FSM}$ Max. Peak One Cycle Non - Repetitive Surge Current	400	A	@ $t_p = 8.3$ ms half-sine

### Electrical Specifications

Parameters	Limits	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop See Fig. 1 ①	0.86	V	@ 20A $T_J = -55^\circ\text{C}$
	0.99	V	@ 35A $T_J = -55^\circ\text{C}$
	0.84	V	@ 20A $T_J = 25^\circ\text{C}$
	0.98	V	@ 35A $T_J = 25^\circ\text{C}$
	0.73	V	@ 20A $T_J = 125^\circ\text{C}$
$I_{RM}$ Max. Reverse Leakage Current See Fig. 2 ①	0.8	mA	$T_J = 25^\circ\text{C}$ $V_R = \text{rated } V_R$
	45	mA	$T_J = 125^\circ\text{C}$ $V_R = \text{rated } V_R$
$C_T$ Max. Junction Capacitance	1400	pF	$V_R = 5V_{DC}$ (1MHz, $25^\circ\text{C}$ )
$L_S$ Typical Series Inductance	7.8	nH	Measured from anode lead to cathode lead 6mm (0.025 in.) from package

### Thermal-Mechanical Specifications

Parameters	Limits	Units	Conditions
$T_J$ Max. Junction Temperature Range	-55 to 150	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
$R_{thJC}$ Max. Thermal Resistance, Junction to Case	1.0	$^\circ\text{C}/\text{W}$	DC operation See Fig. 4
wt Weight (Typical)	9.3	g	
Die Size	200X200	mils	
Case Style	TO-254AA		

① Pulse Width < 300 $\mu\text{s}$ , Duty Cycle < 2%

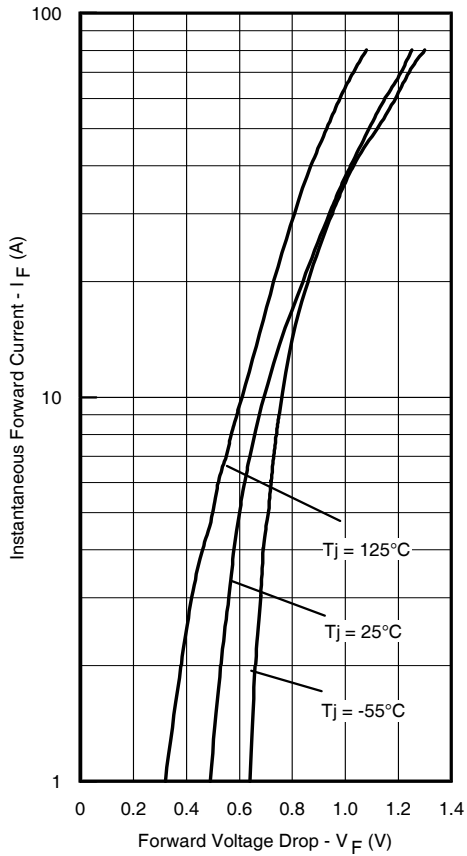


Fig. 1 - Maximum Forward Voltage Drop Characteristics

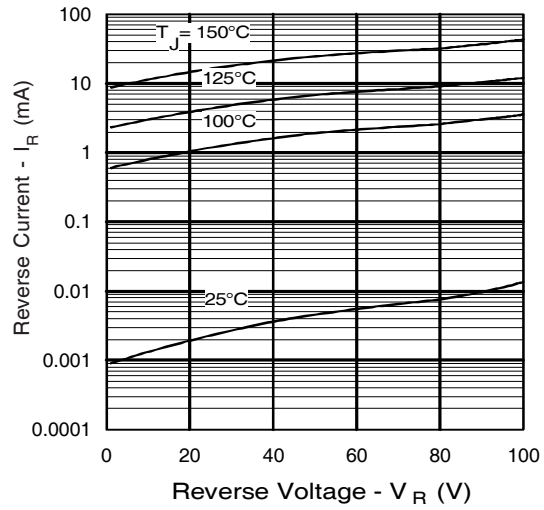


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

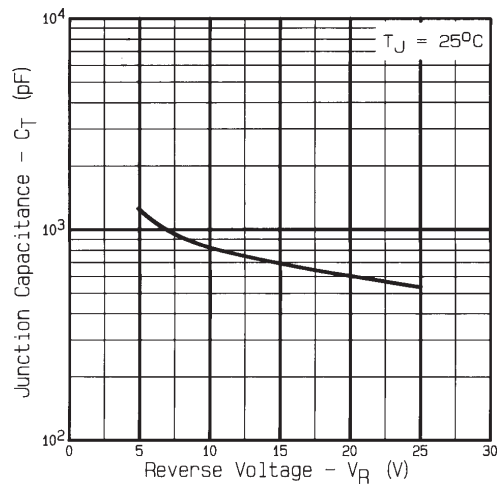


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

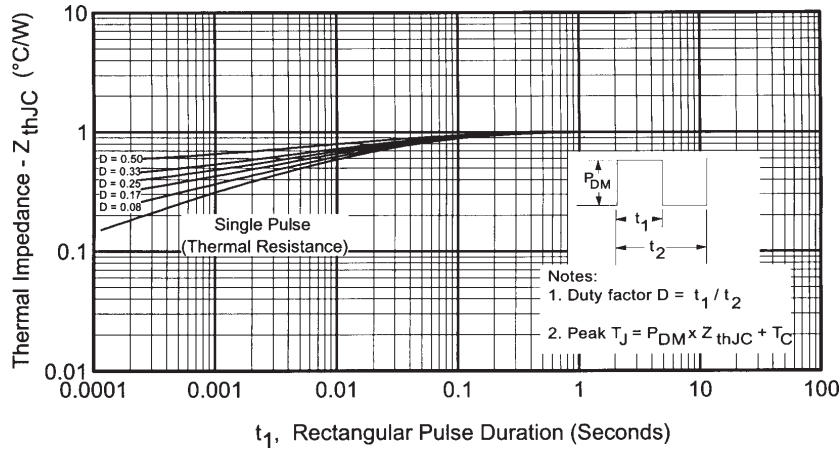


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics

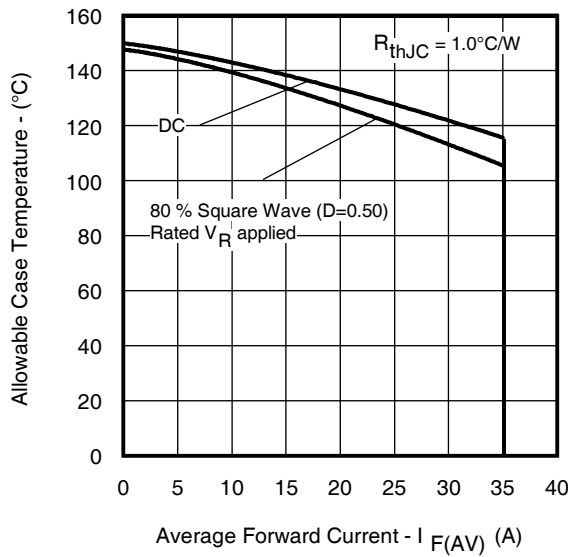


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current